

GS5A - GS5M SURFACE MOUNT RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 5.0 A

Features

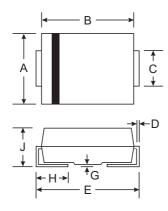
- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: SMC/DO-214AB, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)







SMC/DO-214AB							
Dim	Min	Max					
Α	5.59	6.22					
В	6.60	7.11					
С	2.75	3.18					
D	0.15	0.31					
E	7.75	8.13					
G	0.10	0.20					
Н	0.76	1.52					
J	2.00	2.62					
All Dimensions in mm							

Maximum Ratings and Electrical Characteristics TA = 25°C unless otherwise specified

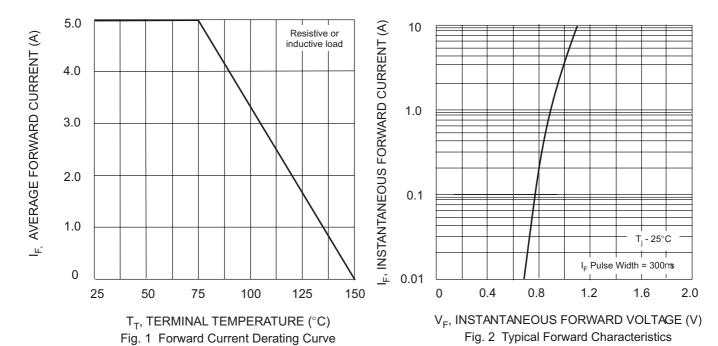
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

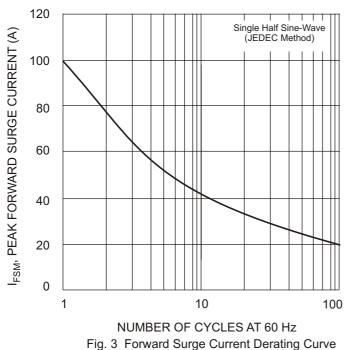
Characteristic		Symbol	GS5A	GS5B	GS5D	GS5G	GS5J	GS5K	GS5M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage		VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current	@T _L = 75°C	lo	lo 5.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	100							А
Forward Voltage	@I _F = 5.0A	VFM	1.15							V
Peak Reverse Current At Rated DC Blocking Voltage	@T _A = 25°C @T _A = 125°C	IRM	10 250							μΑ
Typical Junction Capacitance (No	te 1)	Cj				40				pF
Typical Thermal Resistance (Note	2)	R_{θ} JL				10				°C/W
Operating and Storage Temperature Range		Тj, Tsтg	-65 to +150							°C

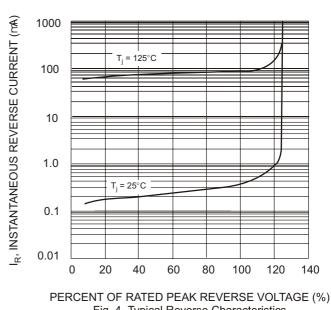
Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.

2. Mounted on P.C. Board with 8.0mm² land area.









单击下面可查看定价,库存,交付和生命周期等信息

>>SUNMATE(森美特)